

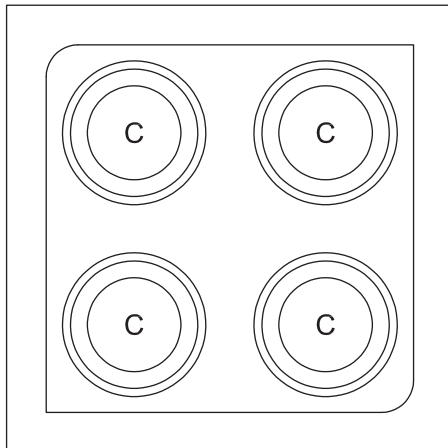
PROCESS CPZ39R
Transient Voltage Suppressor
5 Volt Quad TVS Chip



PROCESS DETAILS

Die Size	11 x 11 MILS
Die Thickness	3.94 MILS
Cathode Bonding Pad Areas (4)	3.54 MILS DIAMETER EACH
Top Side Metalization	Al - 30,000Å
Back Side Metalization	Au - 9,000Å

GEOMETRY



BACKSIDE ANODE R0

GROSS DIE PER 5 INCH WAFER

140,490

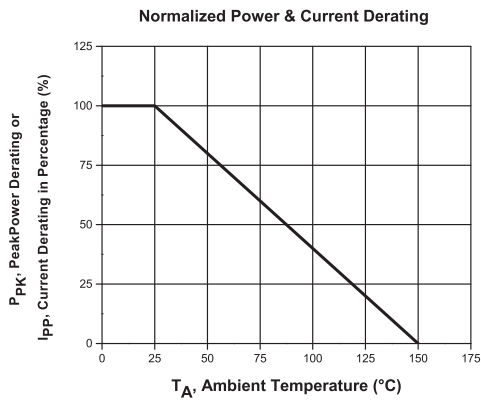
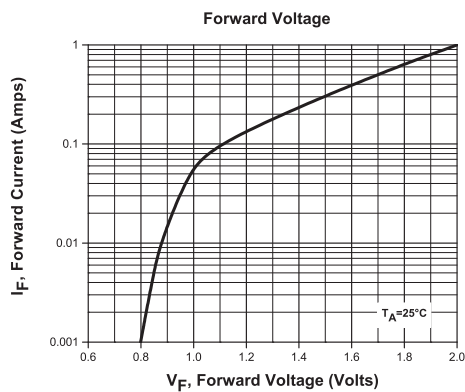
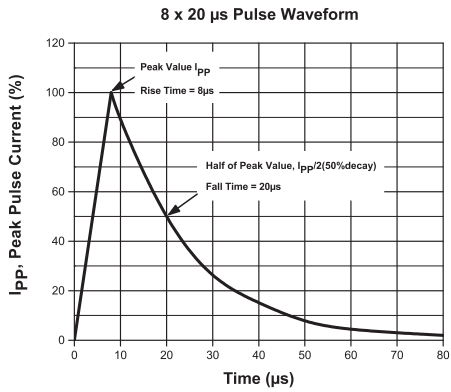
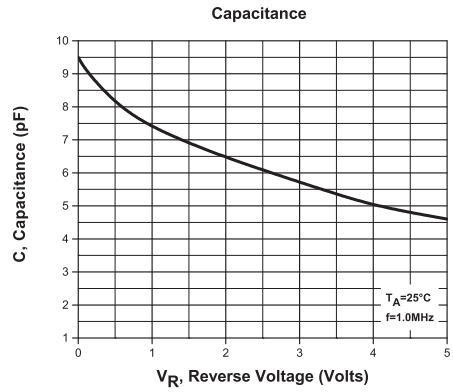
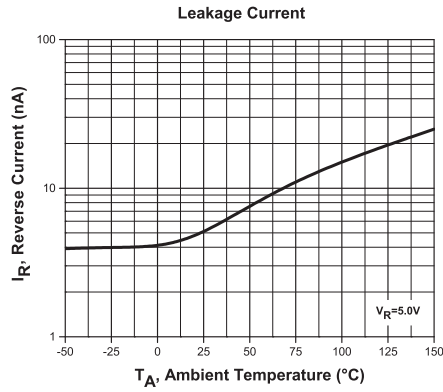
PRINCIPAL DEVICE TYPE

CMNTVS5V0

R0 (22-January 2013)

PROCESS CPZ39R

Typical Electrical Characteristics



R0 (22-January 2013)